Dual 2-input AND Gates

HITACHI

ADE-205-665 (Z)

Rev.0 Jan. 2002

Description

The HD74LV2GT08A has dual two-inputs AND gates in a 8 pin package. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

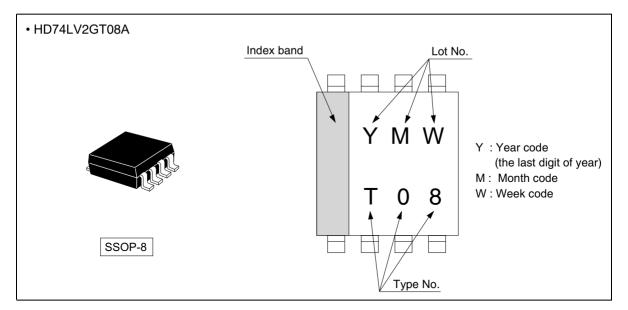
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level.
 - Supply voltage range: 4.5 to 5.5 V
 - Operating temperature range : -40 to +85°C
- All inputs V_{H} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Output current $\pm 12 \text{ mA}$ (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Package type

Package type	Package code	Package suffix	Taping code
SSOP-8 pin	TTP-8DB	US	E (3,000 pcs / Reel)



Outline and Article Indication



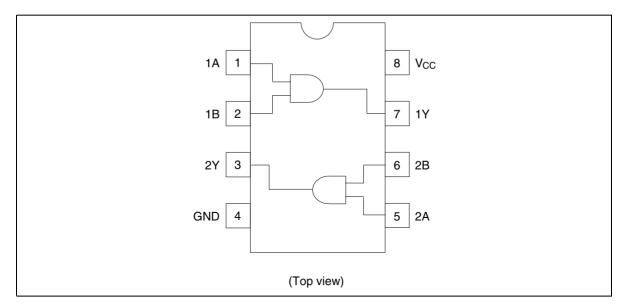
Function Table

Inputs		Output Y
A	В	_
L	L	L
Н	L	L
L	Н	L
Н	Н	Н

H : High level

L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	–0.5 to 7.0	V	
Input voltage range *1	V _I	-0.5 to 7.0	V	
Output voltage range *1, 2	V _o	-0.5 to V_{cc} +0.5	V	Output : H or L
		-0.5 to 7.0		V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{ok}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±25	mA	$V_o = 0$ to V_{cc}
Continuous current through V_{cc} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) '3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes:

- The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit
Supply voltage	V _{cc}	4.5 to 5.5	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{out}	0 to V _{cc}	V
Operating temperature	T _{opr}	-40 to +85	°C
Input rise / fall time	t _r , t _f	0 to 20 (V _{cc} = 4.5 to 5.5 V)	ns

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	4.5 to 5.5	2.0	_	_	V	
	V _{IL}	4.5 to 5.5	_	_	0.8		
Hysteresis voltage	V _H	5.0	_	0.15	_	V	$V_T^+ - V_T^-$
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1	_	_	V	$I_{OH} = -50 \mu A$
		4.5	3.8	_	_		I _{OH} = -12 mA
	V _{OL}	Min to Max	_	_	0.1	_	$I_{OL} = 50 \mu A$
		4.5	_	_	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{cc}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
	ΔI_{cc}	5.5	_	_	1.5	mA	One input $V_{IN} = 3.4 \text{ V}$, other input V_{CC} or GND
Output leakage current	OFF	0	_	_	5	μΑ	V _o = 5.5 V
Input capacitance	C _{IN}	5.0	_	2.5	_	рF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{cc} = 5.0 \pm 0.5 \text{ V}$

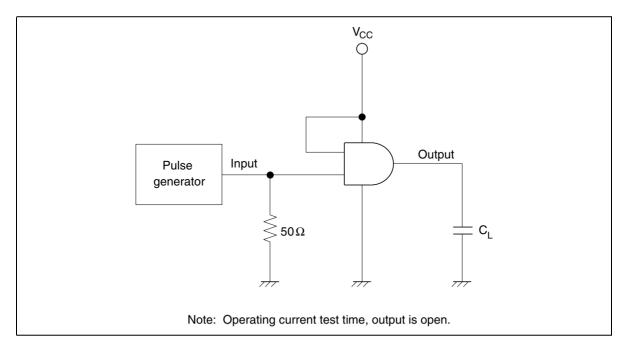
Item	Symbol	Ta = 2	25°C	Ta = -40 to 85°C		Unit		FROM	ТО	
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	5.0	6.9	1.0	8.0	ns	C _L = 15 pF	A or B	Υ
delay time	t _{PHL}	_	5.5	7.9	1.0	9.0	_	C _L = 50 pF	_	

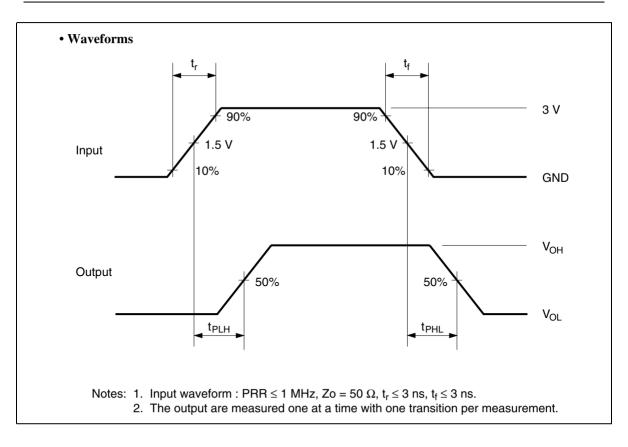
Operating Characteristics

• $C_1 = 50 \text{ pF}$

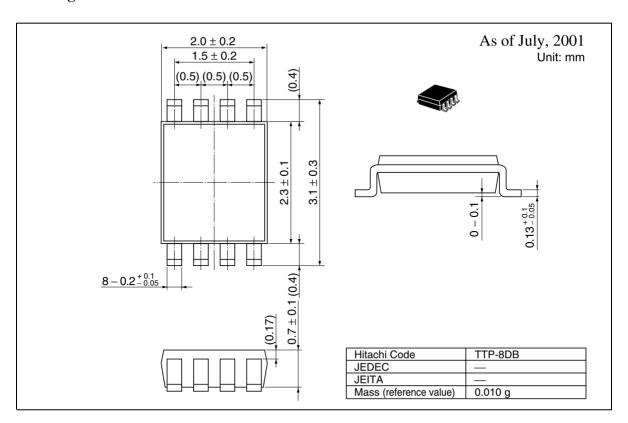
Item	Symbol	$V_{cc}(V)$	Ta = 25°C			Unit	Test Conditions
			Min	Тур	Max		
Power dissipation capacitance	C_{\scriptscriptstylePD}	5.0	_	10.0	_	pF	f = 10 MHz

Test Circuit





Package Dimensions



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